

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150 Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

Mecnanical Data

- * Case :JEDEC ITO-220AB molded plastic body
- * Termals:Plated lead, solderable per MIL-STD-750, Method 2026
- * Polarity: As marked
- * Mounting Torqure: 5 in-lbs. Max.
- * Weight: 1.7 g approx.



Plating pb free is indicated by box

MAXIMUM RATINGS

Characteristic	Symbol	SRF10150C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	150	V
RMS Reverse Voltage	$V_{R(RMS)}$	105	V
Average Rectifier Forward Current Total Device (Rated V_R), T_C =100	I _{F(AV)}	5 10	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	10	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	125	А
Operating and Storage Junction Temperature Range	T_J , T_{STG}	-65 to +150	

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	R _{θ j-c}		
Per diode	•	4.2	/w
Total		3.2	/ VV
Coupling	R _{θ c}	3.0	

Where the diodes1 and 2 are used simultaneously:

 $T_J(diode\ 1) = P(diode\ 1) \times R_{\theta(i-c)}(Per\ diode) + P(diode\ 2) \times R_{\theta\ c}$

ELECTRIAL CHARACTERISTICS

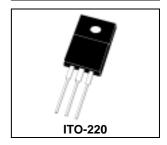
LEES TRIAL STIARASTERISTICS				
Characteristic	Symbol	SRF10150C	Unit	
Maximum Instantaneous Forward Voltage ($I_F = 5.0 \text{ Amp } T_C = 25$) ($I_F = 5.0 \text{ Amp } T_C = 125$)	V _F	0.95 0.85	V	
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25) (Rated DC Voltage, T _C = 125)	I _R	0.2 10	mA	

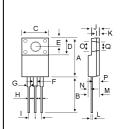
To evaluation the conduction losses use the following equation:

 $P=0.68 \times I_{F(AV)} + 0.015 \times I_{F(RMS)}^{2}$

SCHOTTKY BARRIER RECTIFIERS

10 AMPERES 150 VOLTS





	MILLIMETERS		
DIM	MIN	MAX	
Α	15.05	15.15	
В	13.35	13.45	
C	10.00	10.10	
D	6.55	6.65	
Ē	2.65	2.75	
F	1.55	1.65	
G	1.15	1.25	
H	0.55	0.65	
ı	2.50	2.60	
J	3.00	3.20	
K	1.10	1.20	
L	0.55	0.65	
М	4.40	4.60	
N	1.15	1.25	
Р	2.65	2.75	
0	3.35	3.45	
Q	3.15	3.25	

